



**THE DATASHEET OF  
RSS090P03FU6TB**



## Switching (–30V, –9.0A)

## RSS090P03

## ●Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (SOP8).

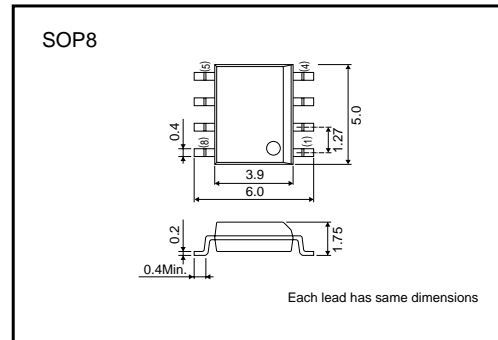
## ●Application

Power switching, DC / DC converter.

## ●Structure

Silicon P-channel  
MOS FET

## ●External dimensions (Unit : mm)



## ●Packaging specifications

Type	Package	Taping
	Code	TB
	Basic ordering unit (pieces)	2500
RSS090P03		○

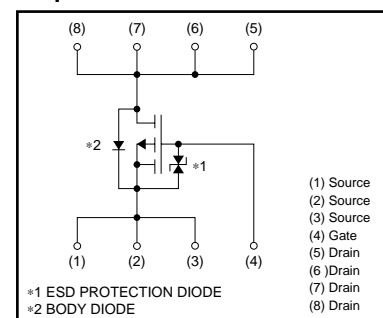
## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DS}$	–30	V
Gate-source voltage	$V_{GS}$	±20	V
Drain current	Continuous	$I_D$	±9.0 A
	Pulsed	$I_{DP}$	±36 A *1
Source current (Body diode)	Continuous	$I_S$	–1.6 A
	Pulsed	$I_{SP}$	–36 A *1
Total power dissipation	$P_D$	2.0	W *2
Channel temperature	$T_{ch}$	150	°C
Range of Storage temperature	$T_{stg}$	–55 to +150	°C

\*1  $P_W \leq 10 \mu s$ , Duty cycle  $\leq 1\%$

\*2 Mounted on a ceramic board

## ●Equivalent circuit



## ●Thermal resistance (Ta=25°C)

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$	62.5	°C / W *

\* Mounted on a ceramic board.

## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	–	–	$\pm 10$	$\mu A$	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	–30	–	–	V	$I_D = -1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	–	–	–1	$\mu A$	$V_{DS} = -30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	–1.0	–	–2.5	V	$V_{DS} = -10V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	–	10	14	$m\Omega$	$I_D = -9.0A, V_{GS} = -10V$
		–	15	21	$m\Omega$	$I_D = -4.5A, V_{GS} = -4.5V$
		–	17	23	$m\Omega$	$I_D = -4.5A, V_{GS} = -4.0V$
Forward transfer admittance	$ Y_{fs} $ *	6.0	–	–	S	$V_{DS} = -10V, I_D = -4.5A$
Input capacitance	$C_{iss}$	–	4000	–	pF	$V_{DS} = -10V$
Output capacitance	$C_{oss}$	–	750	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{rss}$	–	580	–	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$ *	–	25	–	ns	$I_D = -4.5A$
Rise time	$t_r$ *	–	50	–	ns	$V_{DD} = -15V$
Turn-off delay time	$t_{d(off)}$ *	–	150	–	ns	$V_{GS} = -10V$
Fall time	$t_f$ *	–	80	–	ns	$R_L=3.3\Omega$
Total gate charge	$Q_g$	–	39	–	nC	$V_{DD} = -15V$
Gate-source charge	$Q_{gs}$	–	7.0	–	nC	$V_{GS} = -5V$
Gate-drain charge	$Q_{gd}$	–	15	–	nC	$I_D = -9.0A$

\*Pulsed

## Body diode characteristics (source-drain characteristics)

Forward voltage	$V_{SD}$	–	–	–1.2	V	$I_S = -1.6A, V_{GS}=0V$
-----------------	----------	---	---	------	---	--------------------------

Transistors

●Electrical characteristic curves

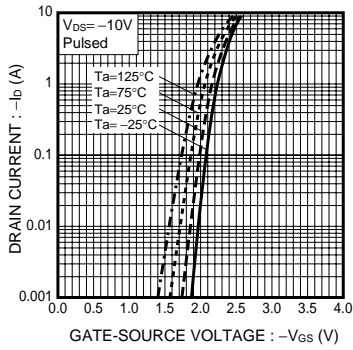


Fig.1 Typical Transfer Characteristics

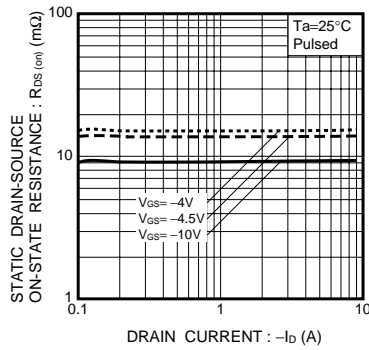


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

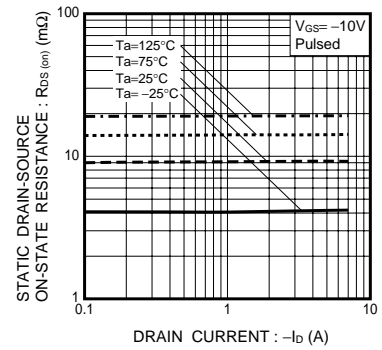


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

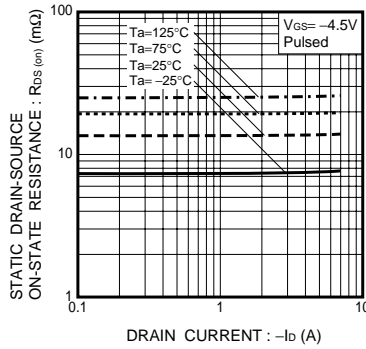


Fig.4 Static Drain-Source On-State vs. Drain Current

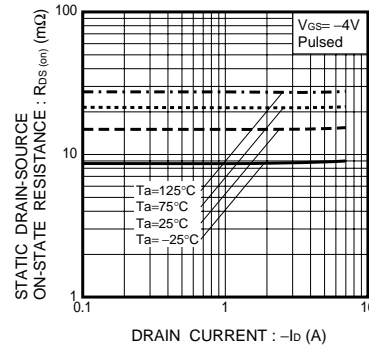


Fig.5 Static Drain-Source On-State vs. Drain Current

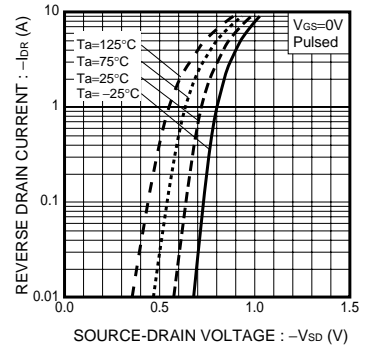


Fig.6 Reverse Drain Current Source-Drain Current

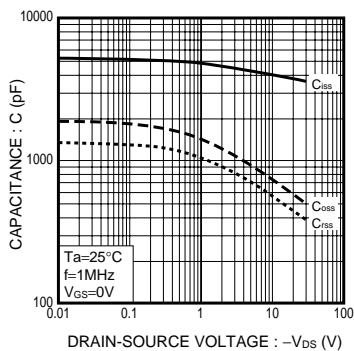


Fig.7 Typical Capacitance vs. Drain-Source Voltage

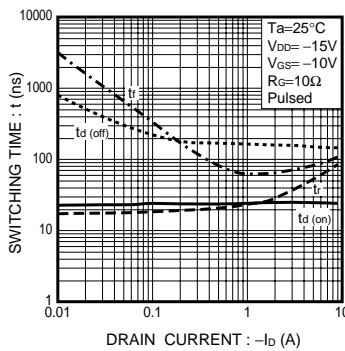


Fig.8 Switching Characteristics

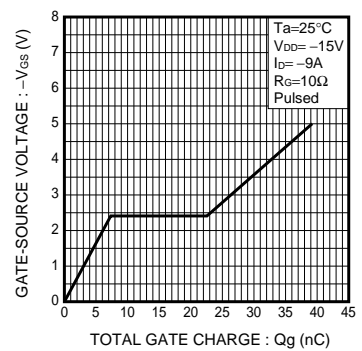


Fig.9 Dynamic Input Characteristics

Transistors

●Measurement circuits

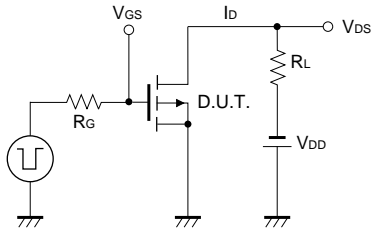


Fig.10 Switching Time Test Circuit

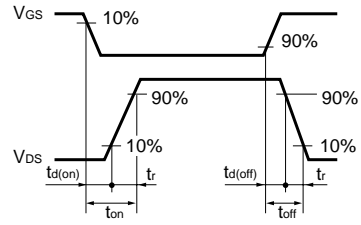


Fig.11 Switching Time Waveforms

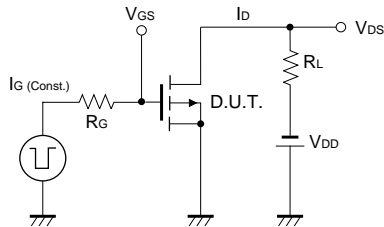


Fig.12 Gate Charge Test Circuit

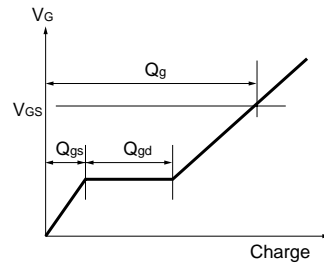


Fig.13 Gate Charge Waveform

### Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

#### About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View RSS090P03FU6TB](#) on WIN SOURCE
- ⊖ [Rohm Semiconductor](#) Information

## Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management